# MC74HC32A

Quad 2-Input OR Gate

High−Performance Silicon−Gate CMOS

The MC74HC32A is identical in pinout to the LS32. The device inputs are compatible with Standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance With the JEDEC Standard No. 7 A Requirements
- Chip Complexity: 48 FETs or 12 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

LOGIC DIAGRAM

$Y = A + B$

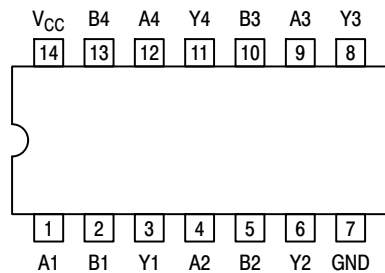PIN 14 = V_{CC}
PIN 7 = GND

ON Semiconductor®

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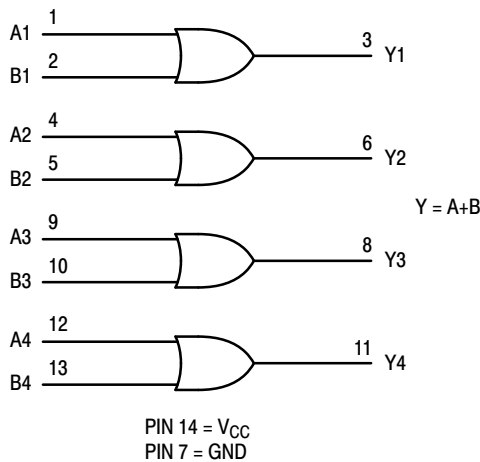
SOIC−14 NB
D SUFFIX
CASE 751A

TSSOP−14
DT SUFFIX
CASE 948G

PIN ASSIGNMENT

V_{CC}	B4	A4	Y4	B3	A3	Y3
14	13	12	11	10	9	8
1	2	3	4	5	6	7
A1	B1	Y1	A2	B2	Y2	GND

14−Lead (Top View)

MARKING DIAGRAMS

SOIC−14 NB

HC32AG
AWLYWW

TSSOP−14

HC
32A
ALYW▪
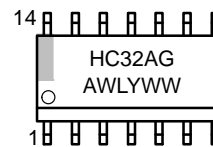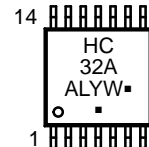
A	= Assembly Location
L, WL	= Wafer Lot
Y, YY	= Year
W, WW	= Work Week
G or ▪	= Pb−Free Package

(Note: Microdot may be in either location)

FUNCTION TABLE

Inputs		Output
A	**B**	**Y**
L	L	L
L	H	H
H	L	H
H	H	H

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

MC74HC32A

MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	−0.5 to +7.0	V
V_{in}	DC Input Voltage (Referenced to GND)	−0.5 to V_{CC} + 0.5	V
V_{out}	DC Output Voltage (Referenced to GND)	−0.5 to V_{CC} + 0.5	V
I_{in}	DC Input Current, per Pin	±20	mA
I_{out}	DC Output Current, per Pin	±25	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	±50	mA
P_D	Power Dissipation in Still Air, SOIC Package† TSSOP Package†	500 450	mW
T_{stg}	Storage Temperature	−65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds Plastic DIP, SOIC or TSSOP Package	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
†Derating: SOIC Package: −7 mW/°C from 65° to 125°C
            TSSOP Package: −6.1 mW/°C from 65° to 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND ≤ (V_{in} or V_{out}) ≤ V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V_{in}, V_{out}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_A	Operating Temperature, All Package Types	−55	+125	°C
t_r, t_f	Input Rise and Fall Time (Figure 1) V_{CC} = 2.0 V V_{CC} = 4.5 V V_{CC} = 6.0 V	0 0 0	1000 500 400	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

MC74HC32A

DC CHARACTERISTICS (Voltages Referenced to GND)

Symbol	Parameter	Condition	V_{CC} V	Guaranteed Limit			Unit
				−55 to 25°C	≤85°C	≤125°C	
V_{IH}	Minimum High−Level Input Voltage	V_{out} = 0.1V or V_{CC} −0.1V $|I_{out}| \leq 20\mu A$	2.0 3.0 4.5 6.0	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	V
V_{IL}	Maximum Low−Level Input Voltage	V_{out} = 0.1V or V_{CC} − 0.1V $|I_{out}| \leq 20\mu A$	2.0 3.0 4.5 6.0	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	V
V_{OH}	Minimum High−Level Output Voltage	V_{in} = V_{IH} or V_{IL} $|I_{out}| \leq 20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		V_{in} =V_{IH} or V_{IL} $\quad |I_{out}| \leq 2.4mA$ $\quad |I_{out}| \leq 4.0mA$ $\quad |I_{out}| \leq 5.2mA$	3.0 4.5 6.0	2.48 3.98 5.48	2.34 3.84 5.34	2.20 3.70 5.20	
V_{OL}	Maximum Low−Level Output Voltage	V_{in} = V_{IH} or V_{IL} $|I_{out}| \leq 20\mu A$	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		V_{in} = V_{IH} or V_{IL} $\quad |I_{out}| \leq 2.4mA$ $\quad |I_{out}| \leq 4.0mA$ $\quad |I_{out}| \leq 5.2mA$	3.0 4.5 6.0	0.26 0.26 0.26	0.33 0.33 0.33	0.40 0.40 0.40	
I_{in}	Maximum Input Leakage Current	V_{in} = V_{CC} or GND	6.0	±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	V_{in} = V_{CC} or GND I_{out} = 0μA	6.0	1.0	10	40	μA

AC CHARACTERISTICS (C_L = 50pF, Input t_r = t_f = 6ns)

Symbol	Parameter	V_{CC} V	Guaranteed Limit			Unit
			−55 to 25°C	≤85°C	≤125°C	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Input A or B to Output Y (Figures 1 and 2)	2.0 3.0 4.5 6.0	75 30 15 13	95 40 19 16	110 55 22 19	ns
t_{TLH}, t_{THL}	Maximum Output Transition Time, Any Output (Figures 1 and 2)	2.0 3.0 4.5 6.0	75 27 15 13	95 32 19 16	110 36 22 19	ns
C_{in}	Maximum Input Capacitance		10	10	10	pF

		Typical @ 25°C, V_{CC} = 5.0 V, V_{EE} = 0 V	
C_{PD}	Power Dissipation Capacitance (Per Buffer)*	20	pF

* Used to determine the no−load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

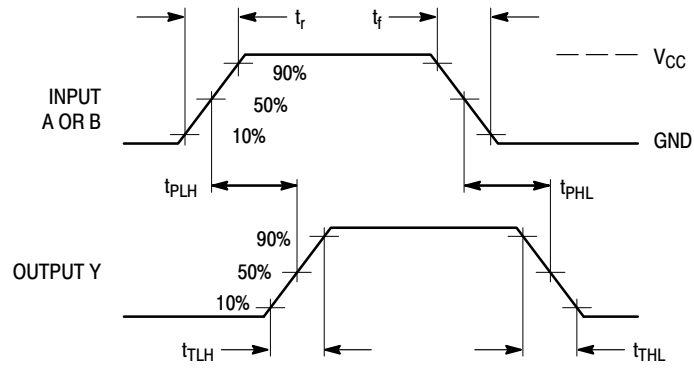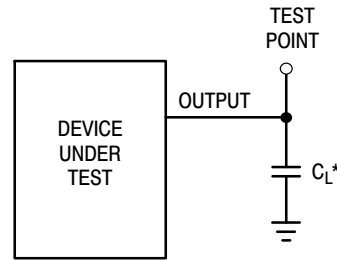**http://onsemi.com**

3

MC74HC32A

Figure 1. Switching Waveforms

*Includes all probe and jig capacitance

Figure 2. Test Circuit
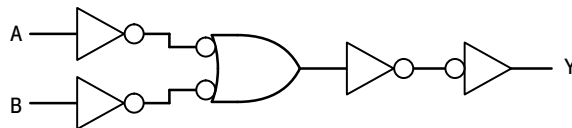
Figure 3. Expanded Logic Diagram
(1/4 of the Device)

MC74HC32A

ORDERING INFORMATION

Device	Package	Shipping†
MC74HC32ADG	SOIC−14 NB (Pb−Free)	55 Units / Rail
MC74HC32ADR2G	SOIC−14 NB (Pb−Free)	2500 / Tape & Reel
MC74HC32ADTR2G	TSSOP−14 (Pb−Free)	2500 / Tape & Reel
NLV74HC32ADG*	SOIC−14 NB (Pb−Free)	55 Units / Rail
NLV74HC32ADR2G*	SOIC−14 NB (Pb−Free)	2500 / Tape & Reel
NLV74HC32ADTR2G*	TSSOP−14 (Pb−Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable

SOIC−14 NB
CASE 751A−03
ISSUE L

DATE 03 FEB 2016

14

1

SCALE 1:1

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

DETAIL A

DETAIL A

SEATING PLANE

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.35	1.75	0.054	0.068
A1	0.10	0.25	0.004	0.010
A3	0.19	0.25	0.008	0.010
b	0.35	0.49	0.014	0.019
D	8.55	8.75	0.337	0.344
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.019
L	0.40	1.25	0.016	0.049
M	0 °	7 °	0 °	7 °

SOLDERING FOOTPRINT*

6.50

14X
1.18

1

1.27
PITCH

14X
0.58

DIMENSIONS: MILLIMETERS

GENERIC MARKING DIAGRAM*

14

XXXXXXXXXG
AWLYWW

1

XXXXX = Specific Device Code
A = Assembly Location
WL = Wafer Lot
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪", may or may not be present.

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42565B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOIC−14 NB		PAGE 1 OF 2

STYLE 1:
PIN 1. COMMON CATHODE
    2. ANODE/CATHODE
    3. ANODE/CATHODE
    4. NO CONNECTION
    5. ANODE/CATHODE
    6. NO CONNECTION
    7. ANODE/CATHODE
    8. ANODE/CATHODE
    9. ANODE/CATHODE
   10. NO CONNECTION
   11. ANODE/CATHODE
   12. ANODE/CATHODE
   13. NO CONNECTION
   14. COMMON ANODE

STYLE 2:
        CANCELLED

STYLE 3:
PIN 1. NO CONNECTION
    2. ANODE
    3. ANODE
    4. NO CONNECTION
    5. ANODE
    6. NO CONNECTION
    7. ANODE
    8. ANODE
    9. ANODE
   10. NO CONNECTION
   11. ANODE
   12. ANODE
   13. NO CONNECTION
   14. COMMON CATHODE

STYLE 4:
PIN 1. NO CONNECTION
    2. CATHODE
    3. CATHODE
    4. NO CONNECTION
    5. CATHODE
    6. NO CONNECTION
    7. CATHODE
    8. CATHODE
    9. CATHODE
   10. NO CONNECTION
   11. CATHODE
   12. CATHODE
   13. NO CONNECTION
   14. COMMON ANODE

STYLE 5:
PIN 1. COMMON CATHODE
    2. ANODE/CATHODE
    3. ANODE/CATHODE
    4. ANODE/CATHODE
    5. ANODE/CATHODE
    6. NO CONNECTION
    7. COMMON ANODE
    8. COMMON CATHODE
    9. ANODE/CATHODE
   10. ANODE/CATHODE
   11. ANODE/CATHODE
   12. ANODE/CATHODE
   13. NO CONNECTION
   14. COMMON ANODE

STYLE 6:
PIN 1. CATHODE
    2. CATHODE
    3. CATHODE
    4. CATHODE
    5. CATHODE
    6. CATHODE
    7. CATHODE
    8. ANODE
    9. ANODE
   10. ANODE
   11. ANODE
   12. ANODE
   13. ANODE
   14. ANODE

STYLE 7:
PIN 1. ANODE/CATHODE
    2. COMMON ANODE
    3. COMMON CATHODE
    4. ANODE/CATHODE
    5. ANODE/CATHODE
    6. ANODE/CATHODE
    7. ANODE/CATHODE
    8. ANODE/CATHODE
    9. ANODE/CATHODE
   10. ANODE/CATHODE
   11. COMMON CATHODE
   12. COMMON ANODE
   13. ANODE/CATHODE
   14. ANODE/CATHODE

STYLE 8:
PIN 1. COMMON CATHODE
    2. ANODE/CATHODE
    3. ANODE/CATHODE
    4. NO CONNECTION
    5. ANODE/CATHODE
    6. ANODE/CATHODE
    7. COMMON ANODE
    8. COMMON ANODE
    9. ANODE/CATHODE
   10. ANODE/CATHODE
   11. NO CONNECTION
   12. ANODE/CATHODE
   13. ANODE/CATHODE
   14. COMMON CATHODE

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DESCRIPTION:	SOIC−14 NB		PAGE 2 OF 2

MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

TSSOP−14 WB
CASE 948G
ISSUE C

DATE 17 FEB 2016

14

SCALE 2:1

1

14X **K** REF

⊕ | 0.10 (0.004) Ⓜ | T | U Ⓢ | V Ⓢ

⬠ 0.15 (0.006) | T | U Ⓢ

2X **L/2**

L

PIN 1 IDENT.

14 ... 8

1 ... 7

A

−V−

B
−U−

⬠ 0.15 (0.006) | T | U Ⓢ

N

0.25 (0.010)

M

N

F

DETAIL E

K
K1

J J1

SECTION N−N

C

⬠ 0.10 (0.004)
−T− **SEATING PLANE**

D **G** **H**

DETAIL E

−W−

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE −W−.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	–––	1.20	–––	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.50	0.60	0.020	0.024
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0 °	8 °	0 °	8 °

GENERIC MARKING DIAGRAM*

14

XXXX
XXXX
ALYW▪

1

A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot " ▪", may or may not be present.

SOLDERING FOOTPRINT

7.06

1

0.65
PITCH

14X
0.36

14X
1.26

DIMENSIONS: MILLIMETERS

DOCUMENT NUMBER:	98ASH70246A	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**TSSOP−14 WB**	**PAGE 1 OF 1**

PUBLICATION ORDERING INFORMATION

◊

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